

PCN# 20130903003A Qualification of ASESH, TITL and JCAP as Additional Assembly and Test Site for Select Devices Change Notification / Sample Request

Dear Customer:

The purpose of this version A is to retract devices from this change notification. The retraction is for select devices that were inadvertently included and are not affected by this change. We apologize for any inconvenience this may have caused.

This is an announcement of change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages.

This notice does not change the end-of-life status of any product. Should product affected be on a previously issued product withdrawal/discontinuance notice, this notification does not extend the life of that product or change the life time buy offering/discontinuance plan.

We request you acknowledge receipt of this notification within **30** days of the date of this notice. If you require samples to conduct an evaluation, please make any request within the 30 days—samples are not built ahead of the change. Please see the schedule on the following pages for availability dates. You may contact the PCN Manager or your local Field Sales Representative to acknowledge this PCN and request samples.

The changes discussed within this PCN will not take effect any earlier than **90** days from the date of this notification, unless customer agreement has been reached on an earlier implementation of the change. This notification period is per TI's standard process. Any negotiated alternative change requirements will be provided via the customer's defined process. Customers with previously negotiated, special requirements will be handled separately. Any inquiries should be directed to your local Field Sales Representative.

For questions regarding this notice, contact your local Field Sales Representative or the PCN Manager (<u>PCN ww admin team@list.ti.com</u>).

Sincerely,

PCN Team SC Business Services Phone: +1(214) 480-6037 Fax: +1(214) 480-6659

PCN# 20130903003A Attachment: 1

Products Affected:

According to our records, there are the affected device(s) that you have purchased within the past twenty-four (24) months. Technical details of this Product Change follow on the next page(s).

PCN Numbe	N Number: 20130903003A PCN Date: 10/31/201						/31/2013		
Title: Qualification of ASESH, TITL and JCAP as Additional Assembly / Test Site for Select Devices									
Customer Contact:	mer ct: PCN_ww_admin_team@list.ti.com Phone: +1(214)480				80-6037	Dept:	Quality Services		
Change Typ	e:								
Assem	bly Site		Assembly Pro	cess		\boxtimes	Assembly	Materia	ls
Design	l		Electrical Spe	cification			Mechanic	al Specif	ication
Test Si	ite		Packing/Shipp	oing/Label	ing		Test Proc	ess	
⊠ Wafer	Bump Site		Wafer Bump I	Material			Wafer Bu	mp Proce	ess
Wafer	Fab Site		Wafer Fab Ma	terials			Wafer Fal	o Process	5
			Part number of	change					
			PCN	I Details	5				
Description	of Change								
affected by this change. Texas Instruments Incorporated is announcing the qualification of ASESH, TITL and JCAP as additional assembly/test site for select devices listed in the "Product Affected" Section. Cur assembly sites are indicated in the "Changes to Product Identification" tables below. Assem differences are as follows: Group 1 Device: HNT to ASESH Wire type 1.0 Mil Au Mold Compound 450179					AP as				
additional as assembly site differences a Group 1 De Wire type Mold Compo	sembly/test es are indica re as follows vice: HNT to pund	site fo ted in :: b ASE	or select devices the "Changes to SH HI 1.0 M 450	Iisted in t o Product NT Iil Au 179	the "Prod Identifica		Affected" on" tables b AS 1.0 M EN20	Section. elow. A ESH Mil Cu 00515	Current ssembly
additional as assembly site differences a Group 1 De Wire type Mold Compo Group 2 De	sembly/test es are indica re as follows vice: HNT to bund vice: AMKO	site fo ted in :: o ASE R K1	or select devices the "Changes to SH 1.0 M 450 to TITL	Iisted in t o Product NT Iil Au 179	the "Prod Identifica	atic	Affected on" tables b AS 1.0 M EN20	Section. elow. A ESH Mil Cu 00515	Current ssembly
additional as assembly site differences a Group 1 De Wire type Mold Compo Group 2 De	sembly/test es are indica re as follows vice: HNT to bund	site fo ted in :: D ASE R K1	or select devices the "Changes to SH 1.0 M 450 to TITL AMKC	IISTED IN T Product NT 1il Au 179 DR K1	the "Prod Identifica		Affected As on tables b As 1.0 M EN20	Section. elow. A ESH Mil Cu 00515	Current ssembly
additional as assembly site differences a Group 1 De Wire type Mold Compo Group 2 De Lead finish	sembly/test es are indica re as follows vice: HNT to bund vice: AMKO	site fo ted in :: D ASE R K1	sr select devices the "Changes to SH 1.0 M 450 to TITL AMKC Matt	NT NT NT NT NT NR K1 e Sn	the "Prod Identifica		Affected Son	ESH Mil Cu 00515	Current ssembly
additional as assembly site differences a Group 1 De Wire type Mold Compo Group 2 De Lead finish Mold Compo	sembly/test es are indica re as follows vice: HNT to ound vice: AMKO	site fo ted in :: D ASE R K1	or select devices the "Changes to SH 1.0 M 450 to TITL AMKC Matt 10131	NT NT NT NT NR K1 e Sn L9570			Affected" for tables b AS 1.0 M EN20 TI NiP 420	Section. elow. A Mil Cu 00515 TL 2dAu 5442	Current ssembly
additional as assembly site differences a Group 1 De Wire type Mold Compo Group 2 De Lead finish Mold Compo Group 3 De	sembly/test es are indica re as follows vice: HNT to bund vice: AMKO	site fo ted in :: D ASE R K1	sr select devices the "Changes to SH 1.0 M 450 to TITL AMKC Matt 10131	NT NT NT NR K1 e Sn 19570			Affected on" tables b AS 1.0 M EN20 TJ NiP 420	Section. elow. A Mil Cu 00515 CTL 2dAu 5442	Current ssembly
additional as assembly site differences a Group 1 Der Wire type Mold Compo Group 2 Der Lead finish Mold Compo Group 3 Der	sembly/test es are indica re as follows vice: HNT to bund vice: AMKO	site fo ted in :: D ASE R K1	sr select devices the "Changes to SH 1.0 M 450 to TITL Matt 10131	NT NT NI Au 179 NR K1 e Sn 19570			Affected AS	Section. As below. As belo	Current ssembly
additional as assembly site differences a Group 1 De Wire type Mold Compo Group 2 De Lead finish Mold Compo Group 3 De Bump Site	sembly/test es are indica re as follows vice: HNT to bund vice: AMKO	site fo ted in :: D ASE R K1	sr select devices the "Changes to SH 1.0 M 450 to TITL AMKC Matt 10131 STS STS	IISTED IN T OPRODUCT III AU 179 OR K1 e Sn 19570 -AT -BP			Affected" i on" tables b AS 1.0 M EN20 TJ NiP 420 JCAF	Section. elow. A ESH <u>Mil Cu</u> 00515 ITL 2442 P-AT P-AT P-FAB	Current ssembly
additional as assembly site differences a Group 1 De Wire type Mold Compo Group 2 De Lead finish Mold Compo Group 3 De Bump Site Test coverag test MQ. Reason for Continuity of Anticipated	sembly/test es are indica re as follows vice: HNT to bund vice: AMKO bund vice: STS to e, insertions Change: Supply Impact on	site fo ted in :: ASE R K1 JCAF , cond	sr select devices the "Changes to SH 1.0 M 450 to TITL AMKC Matt 10131 S STS litions will rema	I listed in t o Product NT Iil Au 179 OR K1 e Sn 19570 -AT -BP in consiste , Quality	che "Prod Identifica		Affected AS on tables b AS 1.0 M EN20 TI NiP 420 JCAF rent testing ity (Positi	Section. elow. A ESH Mil Cu 00515 CTL PAT P-AT P-AT P-FAB g and ver ve / Ne	Current ssembly

Changes to Product Identification Resulting from this PCN: Group 1 Device: HNT to ASESH

Assembly Site					
Hana Thailand	Assembly Site Origin (22L)	ASO: HNT			
ASE Shanghai	Assembly Site Origin (22L)	ASO: ASH			
ASSEMBLY SITE CODES: HNT =H, ASESH = A					

Group 2 Device: AMKOR K1 to TITL

Assembly Site		
AMKOR Korea K1	Assembly Site Origin (22L)	ASO: AMN
TI Taiwan	Assembly Site Origin (22L)	ASO: TAI
ASSEMBLY SITE CODES: AMN =	=7, TITL $=$ T	

Group 3 Device: SCS to JCAP

Assembly Site		
STATS ChipPAC-AT	Assembly Site Origin (22L)	ASO: STS
JCAP-AT	Assembly Site Origin (22L)	ASO: JCP
ACCEMPLY OFFE CODEC OF		

ASSEMBLY SITE CODES: STS =G, JCAP = P

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 20C: 20:	(1P) SN74LS07NSR (9) 2000 (D) 0336
MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04	(31T)LOT: 3959047MLA (4W) TKY(1T) 7523483SI2
РЕТ. LBL: 5A (L)T0:1750	(P) (2P) REV: (V) 0033317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected: Group 1 Device							
OPA1632DGN	THS3202DGNG4	THS4121IDGN	THS4150CDGNG4				
OPA1632DGNG4	THS3202DGNR	THS4121IDGNG4	THS4150CDGNR				
OPA1632DGNR	THS3202DGNRG4	THS4121IDGNR	THS4150CDGNRG4				
OPA1632DGNRG4	THS4011CDGN	THS4121IDGNRG4	THS4150IDGN				
THS3001CDGN	THS4011CDGNG4	THS4130CDGK	THS4150IDGNG4				
THS3001CDGNG4	THS4011CDGNR	THS4130CDGKG4	THS4150IDGNR				
THS3001CDGNR	THS4011CDGNRG4	THS4130CDGN	THS4150IDGNRG4				
THS3001CDGNRG4	THS4011IDGN	THS4130CDGNG4	THS4151CDGK				
THS3001HVCDGN	THS4011IDGNG4	THS4130CDGNR	THS4151CDGKG4				
THS3001HVCDGNG4	THS4011IDGNR	THS4130CDGNRG4	THS4211DGK				
THS3001HVIDGN	THS4011IDGNRG4	THS4130IDGK	THS4211DGKG4				
THS3001HVIDGNG4	THS4022IDGN	THS4130IDGKG4	THS4211DGN				
THS3001IDGN	THS4022IDGNG4	THS4130IDGKR	THS4211DGNG4				
THS3001IDGNG4	THS4022IDGNR	THS4130IDGKRG4	THS4211DGNR				
THS3001IDGNR	THS4022IDGNRG4	THS4130IDGN	THS4211DGNRG4				
THS3001IDGNRG4	THS4031CDGN	THS4130IDGNG4	THS4222DGK				
THS3062DGN	THS4031CDGNG4	THS4130IDGNR	THS4222DGKG4				
THS3062DGNG4	THS4031CDGNR	THS4130IDGNRG4	THS4222DGN				
THS3110IDGN	THS4031CDGNRG4	THS4131CDGK	THS4222DGNG4				
THS3110IDGNG4	THS4031IDGN	THS4131CDGKG4	THS4222DGNR				
THS3110IDGNR	THS4031IDGNG4	THS4131CDGKR	THS4222DGNRG4				

THS3110IDGNRG4	THS4	031IDG	1IDGNR T		131CDGKRG4	THS45	THS4500IDGK	
THS3111CDGNR	THS4031IDGNRG4		THS4131CDGN		THS45	THS4500IDGKG4		
THS3111CDGNRG4	THS4	S4032CDGN		THS4	HS4131CDGNG4		00IDGN	
THS3111IDGN	THS4	4032CDGNG4		THS4	131CDGNR	THS45	00IDGNG4	
THS3111IDGNG4	THS4	032IDG	iN	THS4	131CDGNRG4	THS45	00IDGNR	
THS3111IDGNR	THS4	032IDG	iNG4	THS4	131IDGK	THS45	00IDGNRG4	
THS3111IDGNRG4	THS4	032IDG	inr	THS4	131IDGKG4	THS45	04DGK	
THS3120CDGN	THS4	032IDG	INRG4	THS4	131IDGKR	THS45	04DGKG4	
THS3120CDGNG4	THS4	121CD0	GK	THS4	131IDGKRG4	THS45	04DGN	
THS3120CDGNR	THS4	121CD0	GKG4	THS4	131IDGN	THS45	04DGNG4	
THS3120CDGNRG4	THS4	121CD0	GKR	THS4	131IDGNG4	THS45	04DGNR	
THS3120IDGN	THS4	121CD0	GKRG4	THS4	131IDGNR	THS45	04DGNRG4	
THS3120IDGNG4	THS4	121CD0	GN	THS4	131IDGNRG4	THS45	05DGK	
THS3121IDGN	THS4	121CD0	GNG4	THS4	140CDGN	THS45	05DGKG4	
THS3121IDGNG4	THS4	121CD0	GNR	THS4	140CDGNG4	THS45	05DGN	
THS3202DGK	THS4	121CD0	GNRG4	THS4	140IDGN	THS45	05DGNG4	
THS3202DGKG4	THS4	121IDG	iΚ	THS4	140IDGNG4	THS45	05DGNR	
THS3202DGKR	THS4	121IDG	iKG4	THS4	140IDGNR	THS45	05DGNRG4	
THS3202DGKRG4	THS4	121IDG	ikr	THS4	140IDGNRG4	THS60	72IDGNR	
THS3202DGN	THS4	THS4121IDGKRG4		THS4	150CDGN	THS60	72IDGNRG4	
Product Affected: Gro	oup 2	Device						
MSP430V250IPZ								
Product Affected: Gro	oup 3	Device						
CDC3RL02YFPR	TPS	22932B	SYFPR	TPS	22932BYFPT			
Qualification Data: Group 1								
This qualification has been	n specifi	cally dev	veloped for	the val	idation of this char	nge. The	qualification data	
validates that the propose	d chang	ge meets	s the applic	able rel	eased technical spo	ecificatio	ns.	
	Qua	al Vehio	cle : THS	3202D	GK (MSL1-260	C)		
		Pac	kage Con	struct	ion Details			
Assembly	Site:	ASESH	1		Mold Com	pound:	EN2000515	
# Pins-Designator, Fa	amily:	8-DGK	, MSOP		Mount Com	pound:	EY1000063	
Lead Finish,	Base	NiPdAu	u, Cu		Bon	d Wire:	1.0 Mil Dia. Cu	
Qualification: 🗌 Pl	an	🛛 Test	Results					
Reliability Test			Condition	าร		S	Sample Size / Fail	
Electrical Characterizati	on		-				Pass	
**Temperature Cycle -			-65C/+1	65C/+150C (500 Cyc)			77/0	
Manufacturability (MQ)			(per mfg	mfg. Site specification) Pass				
Moisture Sensitivity			L1-260C				12/0	
Notes **- Preconditioning sequence: Level 1-260C.								

Reference Qualification								
Qua	Qual Vehicle : LM358ADGKR (MSL1-260C)							
Package Construction Details								
Assembly Site:	e: ASESH Mold Comp			ound: EN2000515				
# Pins-Designator, Family:	8-DGK,	MSOP	Mount Compo	ound:	EY1	000063		
Lead Finish, Base	NiPdAu,	Cu	Bond	Wire:	1.0	Mil Dia.	Cu	
Qualification: 🗌 Plan	🛛 Test R	Results						
Reliability Test	C	Conditions		Sa	ample	e Size /	Fail	
				Lot#	1	Lot#2 Lot#3		
**Steady-state Life Test	1	.50C (168 Hou	rs)	77/0)	77/0	77/0	
**High Temp. Storage Bake	1	.50C (500 Hou	rs)	77/0)	77/0	77/0	
**Biased HAST	1	.30C/85%RH (96 Hours)	77/0)	77/0	77/0	
**Autoclave 121C	1	21C, 2 atm (9	6 Hours)	77/0)	77/0	77/0	
**Temperature Cycle	-	65C/+150C (5	00 Cyc)	77/0)	77/0	77/0	
Solderability	S	Steam age, 8 H	ours	22/0)	22/0	22/0	
Flammability	Μ	1ethod A - UL9	4-0	5/0		5/0	5/0	
Flammability	Μ	1ethod B - IEC	695-2-2	5/0		5/0	5/0	
Flammability	Μ	1ethod C - UL 1	1694	5/0		5/0	5/0	
Salt Atmosphere	2	4 Hours		5/0		5/0	5/0	
Manufacturability (MQ)	((per mfg. Site specification)			5	Pass	Pass	
Moisture Sensitivity	L	.1-260C		12/0)	12/0	12/0	
Notes **- Preconditioning se	equence:	Level 1-260C.						
	Qualifi	ication Data	a: Group 2					
This qualification has been specifi	ically devel	loped for the val	idation of this chang	e. The	quali	fication o	lata	
validates that the proposed chang	ge meets tl	he applicable rel	eased technical spec	ificatior	ns.			
Qual V	Vehicle :	MSP430F479	4IPZ (MSL1-260	()				
	Packa	ge Construct	ion Details					
Assembly Site:	TITL		Mold Compound:			4205442		
# Pins-Designator, Family:	100-PZ,	LQFP	Mount Compound: 4042504					
Lead Finish, Base	NiPdAu,	Cu	Bond	Wire:	0.95	5 Mil Dia	a. Au	
Qualification: 🗌 Plan	🛛 Test R	Results						
Reliability Test	C	Conditions			Sample Size / Fail			
Electrical Characterization		-		Pass				
**Operating Life Test		.50C (300 Hou	rs)	120/0				
**Temperature Cycle		65C/+150C (1	000 Cyc)	77/0				
**High Temp. Storage Bake		.70C (420 Hou	rs)	77/0				
ESD CDM	+	+/-500V		3/0				
ESD HBM	+	+/-2KV			3/0			
ESD MM	+	+/-500V			3/0			
X-ray	Т	Top side only			5/0			
Manufacturability (MQ)	((per mfg. Site specification)			Pass			
Notes **- Preconditioning sequence: Level 1-260C.								

Qualification Data: Group 3						
This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.						
	Qual Ve	hicle : CD3239	(MSL1-260C)			
	Pac	kage Construct	ion Details			
Assembly & Bump Site:	JCAP		Bump Compos	ition:	SnAgCu	
# Pins-Designator, Family:	25-YFI	P, WCSP	Bump Diam	neter:	0.23mm	
Qualification: 🗌 Plan	🛛 Test	Results				
Reliability Test		Conditions		Sample Size / Fail		
				Lot#1	Lot#2	Lot#3
**Steady-state Life Test		150C (300 Hours)		116/0) 116/0	116/0
**High Temp. Storage Bake		150C (1000 Hours)		77/0	77/0	77/0
**Biased HAST		130C/85%RH (96 Hours)		77/0	77/0	77/0
**Unbiased HAST		130C/85%RH (96 Hours)		77/0	77/0	77/0
**Temperature Cycle	-55C/+125C (1000 Cyc)		77/0	77/0	77/0	
Manufacturability (MQ)		(per mfg. Site specification)		Pass	Pass	Pass
Moisture Sensitivity		L1-260C		12/0	12/0	12/0
Notes **- Preconditioning se	equence	e: Level 1-260C.				

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com